

# EMB6 / UMB6N

PNP -100mA -50V Complex Digital Transistors (Bias Resistor Built-in Transistors) Datasheet

Parameter	Tr1 and Tr2
V <sub>CC</sub>	-50V
I <sub>C(MAX.)</sub>	-100mA
R <sub>1</sub>	<b>47</b> kΩ
R <sub>2</sub>	<b>47k</b> Ω

#### Features

- 1) Built-In Biasing Resistors,  $R_1 = R_2 = 47k\Omega$ .
- 2) Two DTA144E chips in one package.
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

## Application

Inverter circuit, Interface circuit, Driver circuit

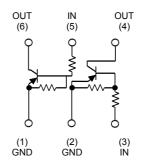
## Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMB6	EMT6	1616	T2R	180	8	8,000	B6
UMB6N	UMT6	2021	TR	180	8	3,000	B6

Outline

EMT6	UMT6
$(1) \underbrace{(2)}_{(2)}^{(6)} \underbrace{(5)}_{(3)}^{(5)} (4)$	$(1)_{(2)}_{(3)}^{(6)}_{(5)}^{(5)}(4)$
EMB6 (SC-107C)	UMB6N SOT-353 (SC-88)

## Inner circuit



## •Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Values	Unit
Supply voltage	V <sub>CC</sub>	-50	V
Input voltage	V <sub>IN</sub>	-40 to +10	V
Output current	Ι <sub>Ο</sub>	-30	mA
Collector current	۲1 ( <sub>C(MAX.)</sub>	-100	mA
Power dissipation	P <sub>D</sub> <sup>*2</sup>	150 (Total) <sup>*3</sup>	mW
Junction temperature	Tj	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

## •Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

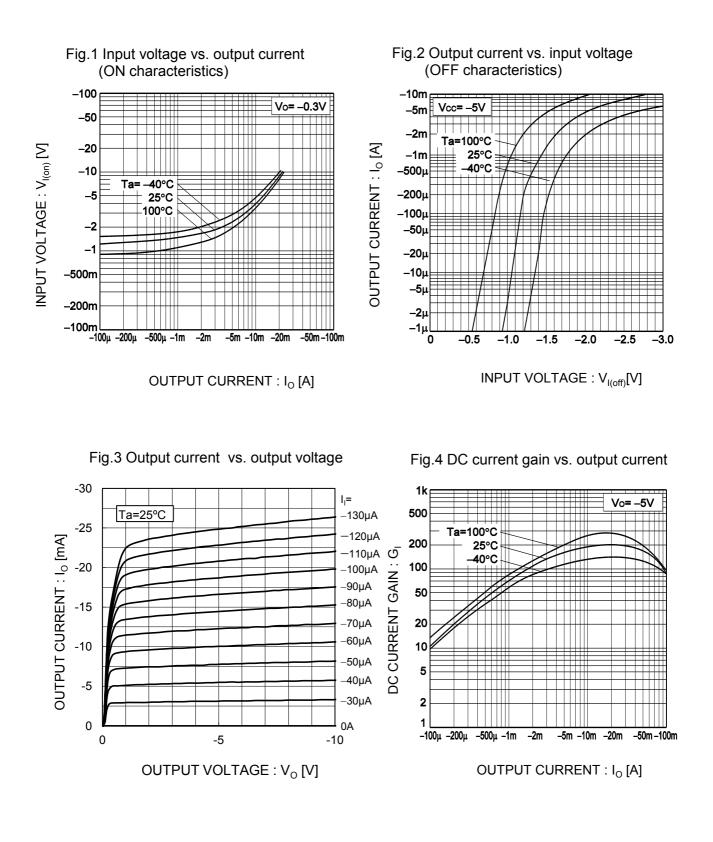
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	V <sub>I(off)</sub>	$V_{CC} = -5V, I_{O} = -100 \mu A$	-	-	-0.5	V
Input voltage	V <sub>I(on)</sub>	$V_0 = -0.3V, I_0 = -2mA$	-3.0	-	-	v
Output voltage	V <sub>O(on)</sub>	I <sub>0</sub> / I <sub>1</sub> = -10mA / -0.5mA	-	-0.1	-0.3	V
Input current	I <sub>I</sub>	V <sub>1</sub> = -5V	-	-	-0.18	mA
Output current	I <sub>O(off)</sub>	$V_{CC} = -50V, V_{I} = 0V$	-	-	-0.5	μA
DC current gain	G <sub>I</sub>	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA	68	-	-	-
Input resistance	R <sub>1</sub>	-	32.9	47	61.1	kΩ
Resistance ratio	$R_2/R_1$	-	0.8	1	1.2	-
Transition frequency	f <sub>T</sub> *1	V <sub>CE</sub> = -10V,  I <sub>E</sub> = 5mA, f = 100MHz	-	250	-	MHz

\*1 Characteristics of built-in transistor

\*2 Each terminal mounted on a reference footprint

\*3 120mW per element must not be exceeded.

#### •Electrical characteristic curves(Ta = 25°C)



## •Electrical characteristic curves(Ta = 25°C)

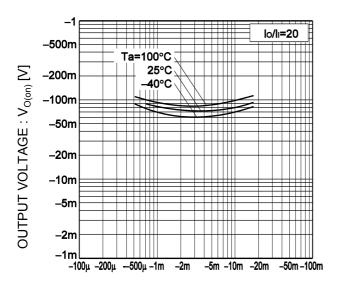
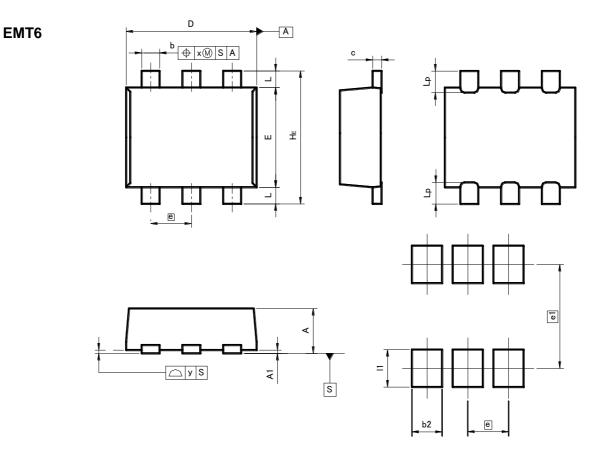


Fig.5 Output voltage vs. output current

OUTPUT CURRENT : Io [A]

#### •Dimensions (Unit : mm)



#### Patterm of terminal position areas

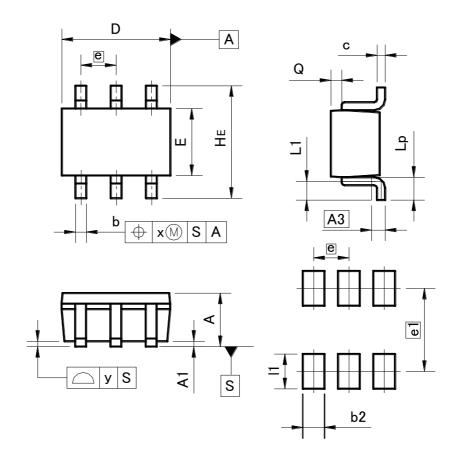
DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
Α	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
с	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
е	0.	50	0.02	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	_	0.35	_	0.014
x	-	0.10	_	0.004
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
e1	1.25		0.049	
b2	-	0.37	-	0.015
1	-	0.45	-	0.018

Dimension in mm/inches

#### •Dimensions (Unit : mm)

UMT6



#### Patterm of terminal position areas

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
А	0.80	1.00	-	0.039
A1	0.00	0.10	0	0.004
A3	0.	25	0.0	01
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
Е	1.15	1.35	0.045	0.053
е	0.	65	0.03	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
х	_	0.10	_	0.004
у	_	0.10	_	0.004

DIM		ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
e1	1.55		0.06	
b2	-	0.40	-	0.016
1	-	0.65	-	0.026

Dimension in mm/inches

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